



PRODUCT SPECIFICATION

Model No : CSM-58211B7/58221B7

Descriptions:

- 2.3 Inch 5X8 Dot-Matrix Display
- Dot Pitch 7.62mm
- CSM-58211: Column Anode, Row Cathode
- CSM-58221: Column Cathode, Row Anode
- Emitting Color: Super Bright Blue



CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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Model No : CSM-58211/58221B7

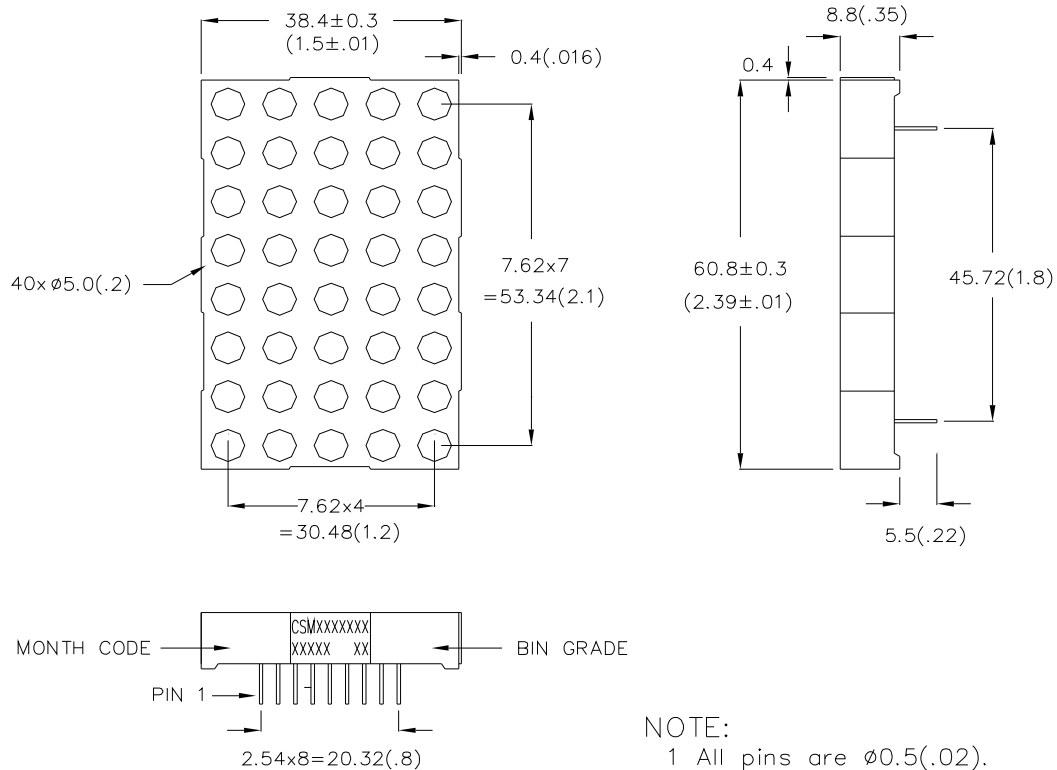
■ Features -

1. 2.3 inch (58.34mm) Matrix height.
2. Case mold type.
3. RoHs compliant.
4. Low power consumption.
5. Easy mounting on P.C. board or socket.

■ Device Selection Guide -

Part No.	Chip		Column	Row
	Material	Emitted Color		
CSM-58211B7	InGaN	Super Bright Blue	Anode	Cathode
CSM-58221B7	InGaN	Super Bright Blue	Cathode	Anode

■ Package Dimensions -



NOTE:

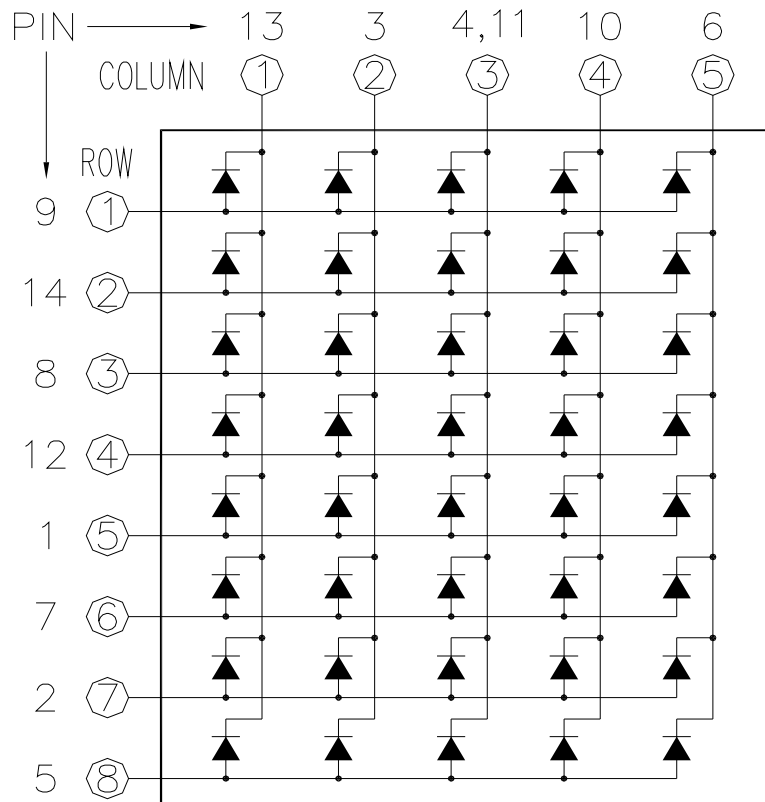
- 1 All pins are $\phi 0.5$ (.02).
- 2 Dimension in millimeters (inch), tolerance is ± 0.25 (.01) unless otherwise noted.



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Internal Circuit Diagrams -

CSM-58221



CSM-58211				CSM-58221			
PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION
1	Cathode Row 5	8	Cathode Row 3	1	Anode Row 5	8	Anode Row 3
2	Cathode Row 7	9	Cathode Row 1	2	Anode Row 7	9	Anode Row 1
3	Anode Column 2	10	Anode Column 4	3	Cathode Column 2	10	Cathode Column 4
4	Anode Column 3	11	Anode Column 3	4	Cathode Column 3	11	Cathode Column 3
5	Cathode Row 8	12	Cathode Row 4	5	Anode Row 8	12	Anode Row 4
6	Anode Column 5	13	Anode Column 1	6	Cathode Column 5	13	Cathode Column 1
7	Cathode Row 6	14	Cathode Row 2	7	Anode Row 6	14	Anode Row 2



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■ Absolute Maximum Rating -

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	Pd	120	mW
Continuous Forward Current Per Dice	IAF	30	mA
Peak Current Per Dice(duty cycle 1/10, 1kHz)	IPF	100	mA
Derating Linear From 25°C Per Dice	-	0.4	mA/°C
Reverse Voltage Per Dice	VR	5	V
Operating Temp.	Topr	-35 ~ +85	°C
Storage Temp.	Tstg	-35 ~ +85	°C
Solder temperature 1/16 inch below seating plane for 3 seconds at 260°C			

■ Electro-optical Characteristics -

(Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment	VF	-	3.3	4	V	IF=20mA
Luminous Intensity Per Segment	Iv	-	35	-	mcd	IF=10mA
Dominant Wavelength	λd	-	470	-	nm	IF=20mA
Spectrum Radiation Bandwidth	Δλ	-	30	-	nm	IF=20mA
Reverse Current	IR	-	-	100	μA	VR=5V
Luminous Intensity Matching Ratio	IV-m	-	-	2:1	-	IF=10mA



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■ Typical Electrical / Optical Characteristics Curves -

(Ta = 25°C Unless Otherwise Noted)

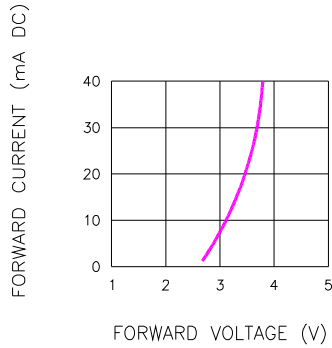


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

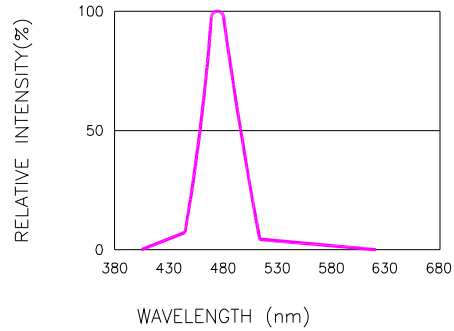


Fig.2 RELATIVE INTENSITY VS. WAVELENGTH

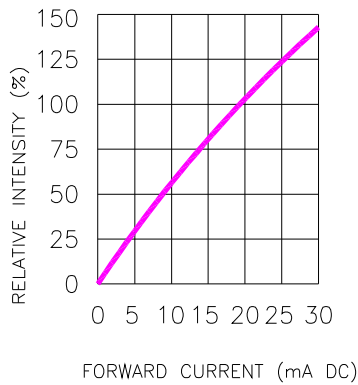


Fig.3 RELATIVE INTENSITY VS. FORWARD CURRENT

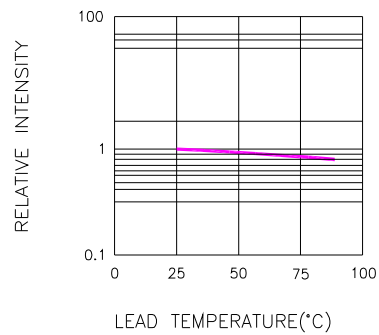


Fig.4 RELATIVE INTENSITY VS. LEAD TEMPERATURE
(PULSED 20 mA; 300us
PULSE, 10ms PERIOD)

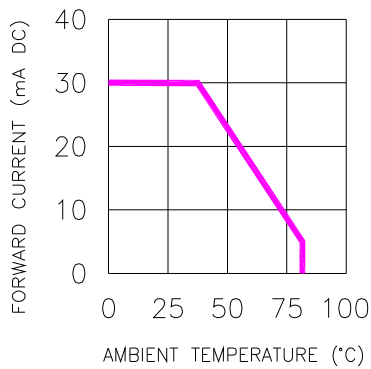


Fig.5 FORWARD CURRENT VS. AMBIENT TEMPERATURE

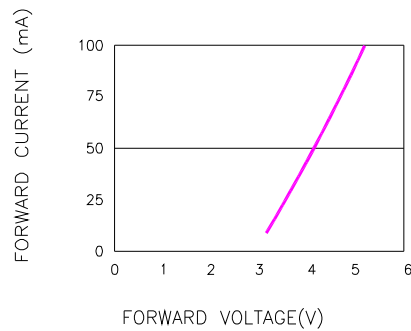


Fig.6 PEAK FORWARD VOLTAGE VS. FORWARD (100us TEST PULSE,
1% DUTY CYCLE)